## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: Tuller et al. GROUP: 2815

SERIAL NO: 10/663,531 EXAMINER: M. Landau

FILED: September 16, 2003

FOR: METHOD FOR P-TYPE DOPING OF WIDE BAND GAP

OXIDE SEMICONDUCTORS

Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

## AMENDMENT

In response to the Office Action mailed July 25, 2007, please amend the aboveidentified application as follows: